

RJK5012DPE

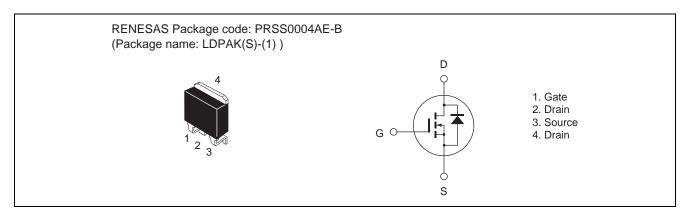
Silicon N Channel MOS FET High Speed Power Switching

REJ03G1487-0300 Rev.3.00 May 12, 2010

Features

- Low on-resistance $R_{DS(on)} = 0.515~\Omega~typ.~(at~I_D=6~A,~V_{GS}=10~V,~Ta=25~^{\circ}C)$
- Low leakage current
- High speed switching

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	500	V
Gate to source voltage	V _{GSS}	±30	V
Drain current	I _D	12	Α
Drain peak current	I _{D (pulse)} Note1	24	Α
Body-drain diode reverse drain current	I _{DR}	12	Α
Body-drain diode reverse drain peak current	I _{DR (pulse)} Note1	24	Α
Avalanche current	I _{AP} Note3	4	Α
Avalanche energy	E _{AR} Note3	0.88	mJ
Channel dissipation	Pch Note2	100	W
Channel to case thermal impedance	θch-c	1.25	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at Tc = 25°C
- 3. STch = 25° C, Tch $\leq 150^{\circ}$ C

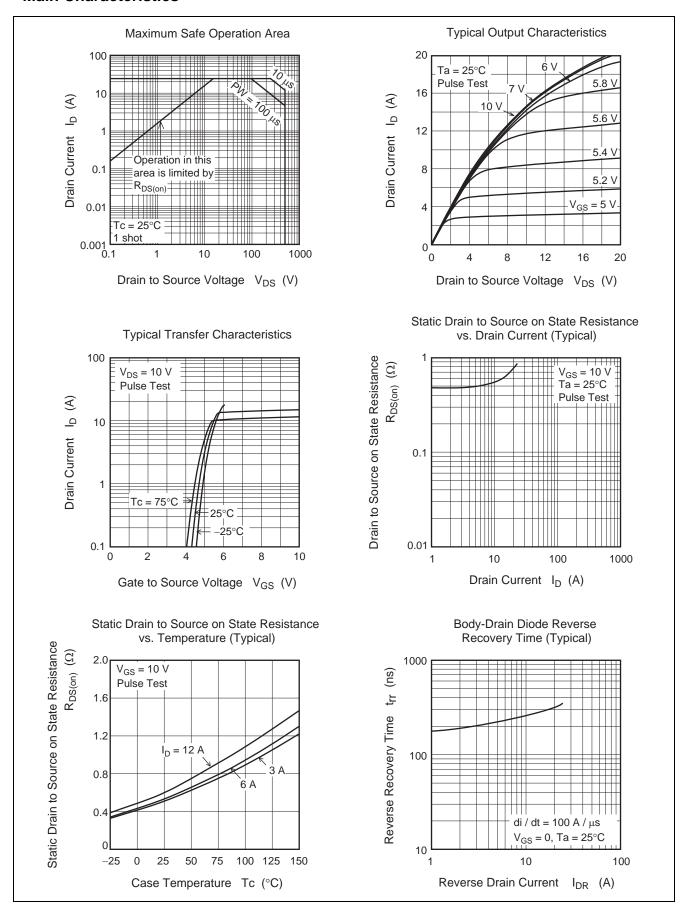
Electrical Characteristics

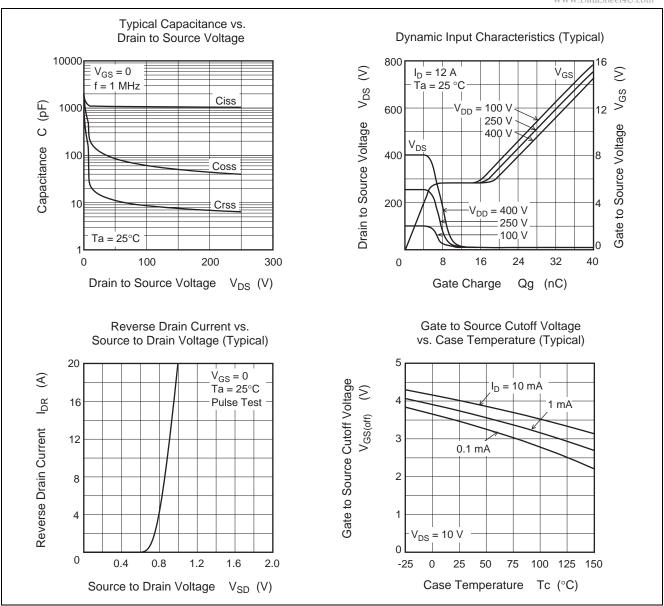
 $(Ta = 25^{\circ}C)$

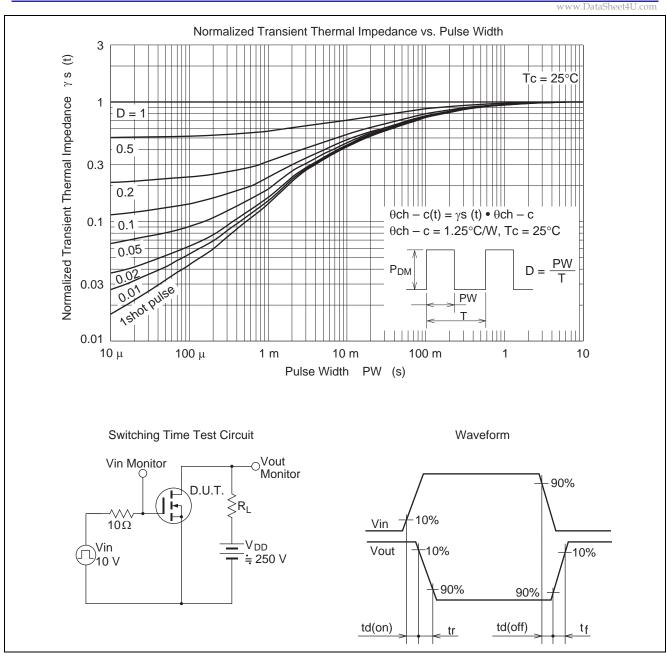
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	500	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 500 \text{ V}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	3.0	_	4.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	0.515	0.620	Ω	$I_D = 6 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance						
Input capacitance	Ciss	_	1100		pF	V _{DS} = 25 V V _{GS} = 0 f = 1 MHz
Output capacitance	Coss		120	_	pF	
Reverse transfer capacitance	Crss	_	15	_	pF	
Turn-on delay time	t _{d(on)}	_	30	_	ns	$I_D = 6 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 41.6 \Omega$ $Rg = 10 \Omega$
Rise time	t _r	_	23	_	ns	
Turn-off delay time	$t_{d(off)}$	_	77	_	ns	
Fall time	t _f	_	16	_	ns	
Total gate charge	Qg	_	29	_	nC	V _{DD} = 400 V V _{GS} = 10 V I _D = 12 A
Gate to source charge	Qgs	_	5.5	_	nC	
Gate to drain charge	Qgd	_	13	_	nC	
Body-drain diode forward voltage	V_{DF}	_	0.89	1.50	V	I _F = 12 A, V _{GS} = 0 Note4
Body-drain diode reverse recovery time	t _{rr}	_	280	_	ns	I _F = 12 A, V _{GS} = 0
						$di_F/dt = 100 A/\mu s$

Notes: 4. Pulse test

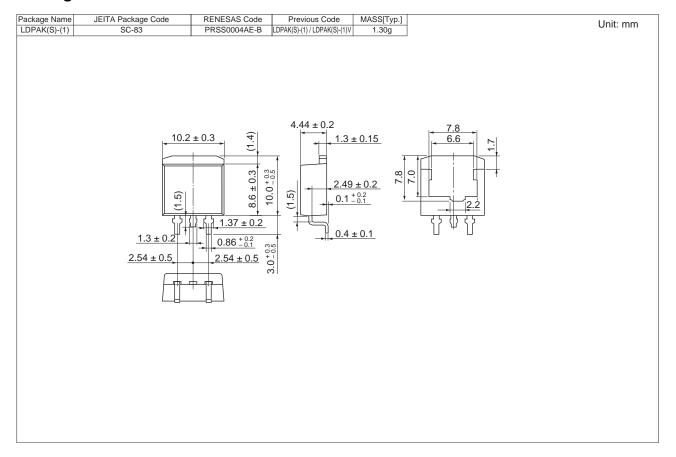
Main Characteristics







Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJK5012DPE-00-J3	1000 pcs	Taping

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